Low Voltage, Dual SPDT Analog Switch with Charge Pump

DESCRIPTION

The DG2616, DG2617, DG2618 are monolithic CMOS analog switching products designed for high performance switching of analog signals. Combining low power, high speed, low on-resistance and small physical size, the DG2616, DG2617, DG2618 are ideal for portable and battery powered applications.

The DG2616, DG2617, DG2618 have built-in charge-pump circuitry which lowers the minimum supply voltage to + 1.5 V while maintaining low on-resistance. The Control circuitry allows the DG2616, DG2617, DG2618 to operate in different configurations.

Built on Vishay Siliconix's low voltage process, the DG2616, DG2617, DG2618 has an epitaxial layer that prevents latch-up. Break-before-make is guaranteed.

The DG2616, DG2617, DG2618 are manufactured in space saving DFN-10 ($3.0 \times 3.0 \text{ mm}$). And as a committed partner to the community and the environment, Vishay Siliconix manufactures this product with lead (Pb)-free device terminations and is 100 % RoHS compliant.

FEATURES

- Low voltage operation (1.5 V to 3.6 V)
- Low on-resistance R_{ON}: 4.2 Ω typ. at 2.7 V
 - Fast switching: t_{ON} = 39 ns
 - t_{OFF} = 8 ns
- DFN-10 package

BENEFITS

- Reduced power consumption
- High accuracy
- Reduce board space
- TTL/1.8 V logic compatible
- High bandwidth

APPLICATIONS

- Cellular phones
- Audio and video signal routing
- PCMCIA cards
- · Battery operated systems

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION

TRUTH TABLE DG2616					
Logic	NC1, 2	NO1, 2			
0	ON	OFF			
1	OFF	ON			

TRUTH TABLE DG2617						
SHDN/EN Logic	IN Logic	NC1, 2	NO1, 2	Charge Pump		
0	0	ON	OFF	ON		
0	1	OFF	ON	ON		
1	0	ON	OFF	OFF		
1	1	OFF	ON	OFF		

TRUTH TABLE DG2618						
SHDN/EN Logic	IN Logic	NC1, 2	NO1, 2	Charge Pump		
0	0	ON	OFF	ON		
0	1	OFF	ON	ON		
1	х	OFF	OFF	OFF		

ORDERING INFORMATION				
Temp. Range	Package	Part Number		
- 40 °C to 85 °C	DFN-10	DG2616DN-T1-E4 DG2617DN-T1-E4 DG2618DN-T1-E4		



RoHS

COMPLIANT



DG2616, DG2617, DG2618

Vishay Siliconix







ABSOLUTE MAXIMUM RATINGS T _A = 25 °C, unless otherwise noted				
Parameter		Limit	Unit	
Reference to GND	V+	- 0.3 to 6.0	V	
Reference to GND	IN, COM, NC, NO ^a	- 0.3 to (V+ + 0.3)	v	
Current (Any terminal except NO, NC or COM)		30		
Continuous Current (NO, NC, or COM)		± 150	mA	
Peak Current (Pulsed at 1 ms, 10 % Duty Cycle)		± 300		
Storage Temperature (D-Suffix)		- 65 to 150	°C	
Package Solder Reflow Conditions ^d				
Power Dissipation (Packages) ^b	DFN-10 ^c	1191	mW	

Notes:

a. Signals on NC, NO, or COM or IN exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.

b. All leads welded or soldered to PC board.

c. Derate 14.9 mW/°C above 70 °C

d. Manual soldering with iron is not recommended for leadless components. The DFN-10 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper lip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.



DG2616, DG2617, DG2618 Vishay Siliconix

SPECIFICATIONS $V + = 3 V$							
		Test Conditions Otherwise Unless Specified		Limits - 40 °C to 85 °C			
Parameter	Symbol	V+ = 3 V, \pm 10 %, V _{IN} = 0.5 or 1.4 V ^e	Temp. ^a	Min. ^b	Typ. ^c	Max. ^b	Unit
Analog Switch	-						
Analog Signal Range ^d	V _{NO} , V _{NC} , V _{COM}		Full	0		V+	V
		V+ = 1.5 V, V _{COM} = 1.5 V, I _{NO} , I _{NC} = 10 mA	Room Full		5.3	7.0 8.0	
On-Resistance	R _{ON}	V+ = 2.7 V, V_{COM} = 1.5 V, I_{NO} , I_{NC} = 10 mA V+ = 2.7 V, V_{COM} = 2.7 V, I_{NO} , I_{NC} = 10 mA	Room		4.2 4.7	7.0	
			Full			8.0	
		V+ = 3.6 V, V _{COM} = 3.6 V, I _{NO} , I _{NC} = 10 mA	Room Full		5.5	7.0 8.0	Ω
R _{ON} Flatness ^d	R _{ON} Flatness	V+ = 2.7 V, V _{COM} = 1.5 V, 2.7 V,	Room		0.6	2.0	
R _{ON} Match ^d	ΔR_{ON}	I _{NO} , I _{NC} = 10 mA	Room		0.1		
On Besistance (Shutdown)	Венры	$V_{\pm} = 3.6 V. V_{COM} = 1.7 V. INO. INC = 10 mA$	Room		15	20	
	- SHDN		Full			21	
	INO(off),	$V_{+} = 3.6 V$ VNO VNO = 0.3 V/3.3 V	Room	-2		2	
Switch Off Leakage Current	'NC(off)	$V_{COM} = 3.3 \text{ V/0.3 V}$	Boom	- 10		2	
	I _{COM(off)}		Full	- 10		10	nA
Channel-On Leakage		$V_{\pm} = 3.6 \text{ V}$ $V_{\pm} = V_{\pm} = 0.3 \text{ V/}3.3 \text{ V}$	Room	- 2		2	
Current	'COM(on)	$v = 3.0$ v, $v_{\rm NO}$, $v_{\rm NC} = v_{\rm COM} = 0.3$ v/3.3 v	Full	- 10		10	
Digital Control							
Input High Voltage	V _{INH}	V+ = 1.5 V		1.0			
		V + = 2.7 V to 3.6 V	Full	1.4			V
Input Low Voltage	V _{INL}	V + = 1.5 V	_			0.4	
Input Capacitance	C _{in}	V+ - 2.7 V to 0.0 V	Full		3.2	0.0	pF
Input Current	I _{INI} or I _{INH}	$V_{IN} = 0 \text{ or } V+$	Full	- 1		1	uA
Dynamic Characteristics							•
.			Room		39	69	
Turn-On Time	LON	$V_{\pm} = 2.7 \text{ or } 3.6 \text{ V}$ V ₁ or V ₁ = 1.5 V	Full			76	
Turn-Off Time	t _{OFF}	$B_1 = 50 \Omega_2 C_1 = 35 \text{ pF}$	Room		9	39	ns
Dural Defens Male Thus	+		Full			41	
Break-Before-Make Time	t _d		Full	1			
Charge Injection ^u	Q _{INJ}	$G_{L} = 1 \text{ nF}, V_{GEN} = 0 \text{ V}, R_{GEN} = 0 \Omega$	Room		/		pC
Off-Isolation ^d	OIRR	$H_{L} = 50.02$, $G_{L} = 5 \text{ pr}$, $f = 1.00 \text{ MHz}$	-		- / /		
		$B_1 = 50 \Omega_2 G_1 = 5 pE f = 1 MHz$	Room		- 32		dB
Crosstalk ^{d, f}	X _{TALK}	$R_1 = 50 \Omega, C_1 = 5 pF, f = 100 MHz$			- 32		
	C _{NO(off)}		Room		9		
N _O , N _C Off Capacitance ^d	C _{NC(off)}	<i>c</i> ,	Room		7		
	C _{NO(on)}	t = 1 MHz	Room		21		pF
Channel-On Capacitance ^d	C _{NC(on)}		Room		19		



SPECIFICATIONS $V + = 3 V$							
		Test Conditions Otherwise Unless Specified		Limits - 40 °C to 85 °C			
Parameter	Symbol	V+ = 3 V, \pm 10 %, V $_{\rm IN}$ = 0.5 or 1.4 V $^{\rm e}$	Temp. ^a	Min. ^b	Typ. ^c	Max. ^b	Unit
Power Supply							
Power Supply Range	V+			1.5		3.6	V
Power Supply Current	L.	V + = 3.6 V, V _{IN} = 0 or V+, SHDN/ \overline{EN} = 0 V	Eull		104	300	
	1+	V + = 3.6 V, V _{IN} = 0 or V+, SHDN/ \overline{EN} = V+	run		0.1	2	μΑ

Notes:

a. Room = 25 $^{\circ}$ C, Full = as determined by the operating suffix.

b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.

c. Typical values are for design aid only, not guaranteed nor subject to production testing.

d. Guarantee by design, not subjected to production test.

e. V_{IN} = input voltage to perform proper function.

f. Crosstalk measured between channels.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



DG2616, DG2617, DG2618

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TYPICAL CHARACTERISTICS $T_A = 25$ °C, unless otherwise noted



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TYPICAL CHARACTERISTICS $T_A = 25$ °C, unless otherwise noted





Loss

VISHAY



DG2616, DG2617, DG2618

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TEST CIRCUITS







Logic "1" = Switch On Logic input waveforms inverted for switches that have the opposite logic sense.







C_L (includes fixture and stray capacitance)

Figure 2. Break-Before-Make Interval





IN depends on switch configuration: input polarity determined by sense of switch.

Figure 3. Charge Injection

TEST CIRCUITS





Figure 4. Off-Isolation

Figure 5. Channel Off/On Capacitance

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